XP02401 (XP2401)

Silicon PNP epitaxial planar type

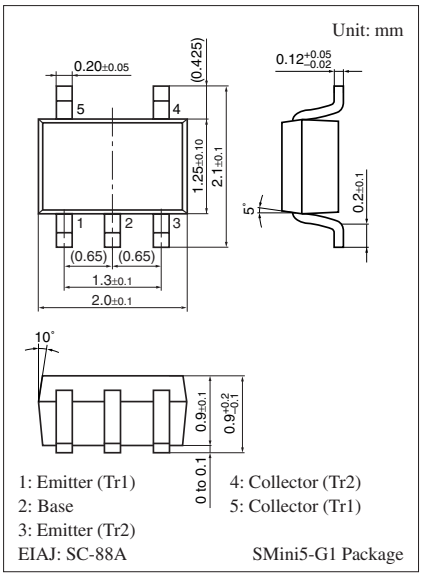
For general amplification

■ Features

- Two elements incorporated into one package (Base-coupled transistors)
- Reduction of the mounting area and assembly cost by one half

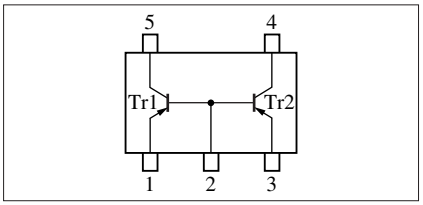
■ Basic Part Number

- 2SB0709A (2SB709A) × 2



Marking Symbol: 7R

Internal Connection



■ Absolute Maximum Ratings $T_a = 25°C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	−60	V
Collector-emitter voltage (Base open)	V_{CEO}	−50	V
Emitter-base voltage (Collector open)	V_{EBO}	−7	V
Collector current	I_C	−100	mA
Peak collector current	I_{CP}	−200	mA
Total power dissipation	P_T	150	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	−55 to +150	°C

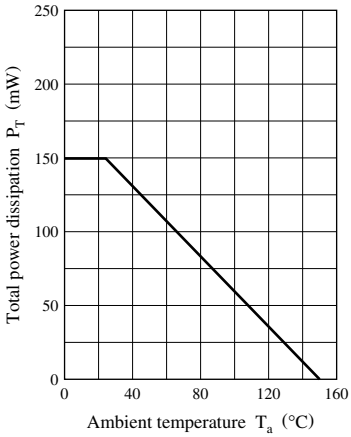
■ Electrical Characteristics $T_a = 25°C \pm 3°C$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = -10$ μA, $I_E = 0$	−60			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = -2$ mA, $I_B = 0$	−50			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = -10$ μA, $I_C = 0$	−7			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -20$ V, $I_E = 0$			− 0.1	μA
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = -10$ V, $I_B = 0$			−100	μA
Forward current transfer ratio	h_{FE}	$V_{CE} = -10$ V, $I_C = -2$ mA	160		460	—
h_{FE} ratio *	$h_{FE(Small/Large)}$	$V_{CE} = -10$ V, $I_C = -2$ mA	0.50	0.99		—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -100$ mA, $I_B = -10$ mA		− 0.3	− 0.5	V
Transition frequency	f_T	$V_{CB} = -10$ V, $I_E = 1$ mA, f = 200 MHz		80		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = -10$ V, $I_E = 0$, f = 1 MHz		2.7		pF

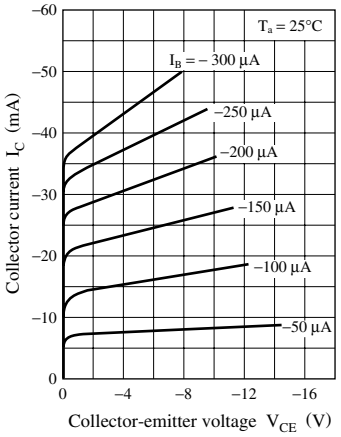
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
2. *: Ratio between 2 elements

Note) The part number in the parenthesis shows conventional part number.

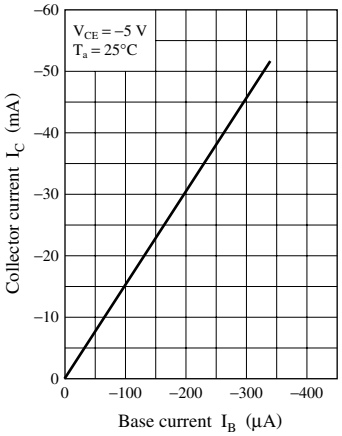
P_T — T_a



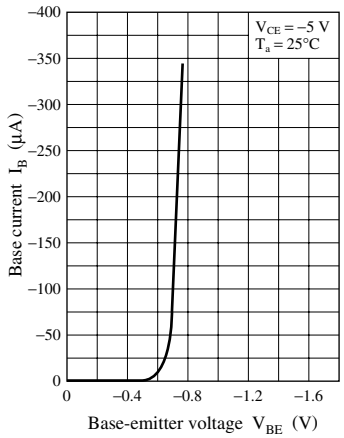
I_C — V_{CE}



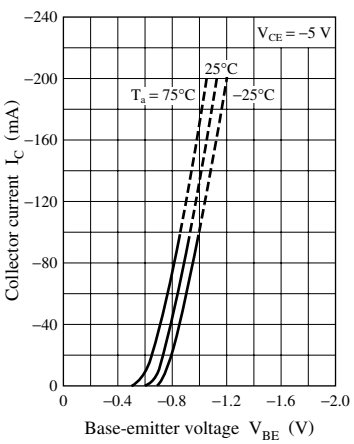
I_C — I_B



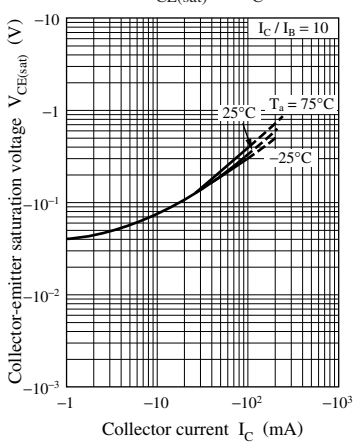
I_B — V_{BE}



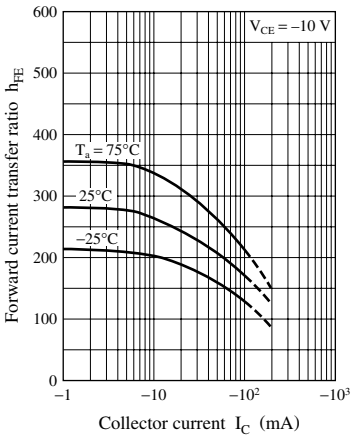
I_C — V_{BE}



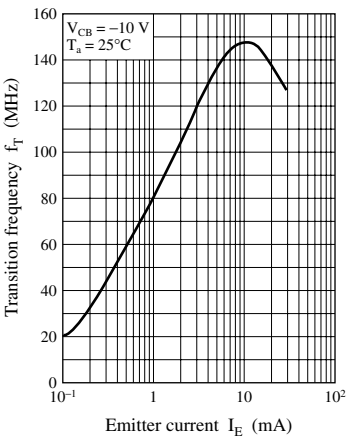
$V_{CE(sat)}$ — I_C



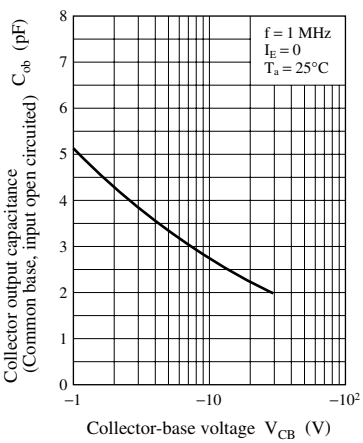
h_{FE} — I_C



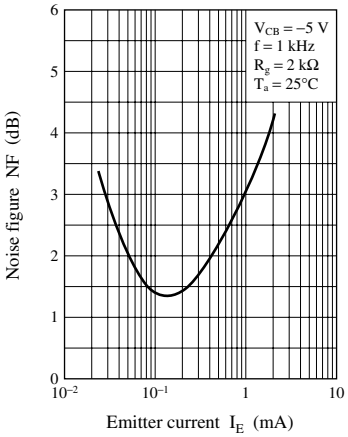
f_T — I_E



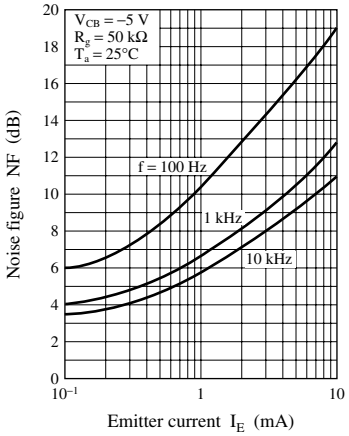
C_{ob} — V_{CB}



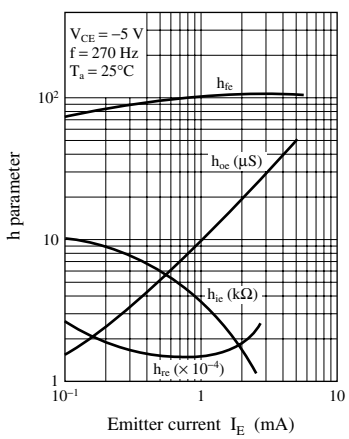
NF — I_E



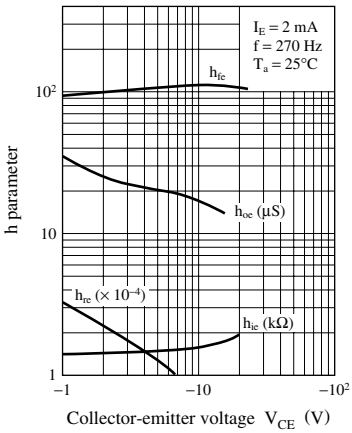
NF — I_E



h parameter — I_E



h parameter — V_{CE}



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